Synthesis and Characterization of (CdO-CuO-Co$_3$O$_4$) Mixed Metal Oxides Nanocomposite

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Abstract

The main goals of this study are to synthesize a mixed metal oxide nanocomposite (NC), CdO-CuO-Co$_3$O$_4$, and to analyze its structural, morphological, optical, and electrical properties using X-ray diffraction (XRD), total reflection X-ray fluorescence (TXRF), transmission electron microscopy (TEM), diffuse reflectance spectroscopy (DRS), and DC electrical resistivity. According to the XRD analysis, CuO nanoparticles (NPs) have a monoclinic structure, while CdO and Co$_3$O$_4$ (NPs) have cubic structures. The TEM images revealed a decrease in the particle size of CdO-CuO-Co$_3$O$_4$ (NC) compared with that of the NPs. The optical properties of CdO-CuO-Co$_3$O$_4$ (NC) were examined using a DRS in the wavelength range of 400-700 nm. The DC electrical resistivity results showed the semiconducting electrical behaviors of the samples.

Article Info

Keywords: CdO-CuO-Co$_3$O$_4$ nanocomposites (NC), TEM, Optical band gap, Electrical resistivity

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1. INTRODUCTION

The primary focus of current nanotechnology research is to synthesize new nanomaterials, which have a variety of intriguing applications in fields such as electrochemistry, biomedicine, catalysis, cosmetics, electronics, and optical devices, as well as in energy science, mechanics, food technology, healthcare, sensors, textile technology, space technology, and pharmaceuticals [1–5]. The synthesis of multi-metal oxides nanocomposites involves mixing more than one oxide at the nanometer scale. These nanocomposites exhibit properties that vary according to the concentration of each constituent oxide in the mixture [1]. The various properties of individual oxides can be greatly improved by mixing different metal oxides (MOs) to form new NCs, which would then improve performance in a variety of technological applications. These characteristics of nanocomposites may play a significant role in a variety of applications, including solar cells, fuel cells, UV detectors, battery materials, gas sensors, photovoltaic devices, and biomedicine. It is common knowledge that new composite materials, which have recently attracted interest in technology, can be produced by combining various compounds with exceptional dielectric characteristics. In addition, a new stage can significantly improve the electronic properties of the resulting composite material. A variety of methods can be used to synthesize nanocomposites, including solid-state mixing [6], electrochemical methods [7], hydrothermal growth [8], sonochemistry [9], the sol-gel technique [10], high-pressure synthesis [11], glycine nitrate combustion [12], co-precipitation methods [13], and thermal evaporation [14]. Through these, the co-precipitation method is utilized because it is effective, simple, and fast; it also reduces the growth of the temperature and does not cost [15]. The special chemical, electrical, and optical properties of cadmium oxide nanoparticles (CdO NPs), an n-type semiconductor with a 2–2.7 eV direct optical bandgap, make it an ideal material for photocatalytic applications [16–19]. Copper oxide (CuO NPs), a p-type semiconductor with a small bandgap (1.2 – 2.4 eV), has significant applications in the development of superca-
pacitors, near-infrared filters, magnetic storage media, sensors, catalysis, and semiconductors [20–23]. Owing to their low price, environmental friendliness, simplicity of preparation, and exceptional chemical and physical stability, cobalt oxide (Co$_2$O$_3$ NPs), a p-type semiconductor with a bandgap of 1.2 – 3.34 eV, has gained more attention in recent years for its effectiveness in the photodegradation of dye pollutants. Additionally, Co$_2$O$_3$ NPs, which are used in various applications such as gas sensors and supercapacitors, have exceptional optical, electrical, and magnetic properties [24–26]. The combination of magnetic Co$_2$O$_3$ with semiconducting CdO and CuO could result in interesting magnetic and electronic behaviors suitable for applications such as sensors or electronic devices. In this study, CdO, CuO, Co$_2$O$_3$ (NPs), and CdO-CuO-Co$_3$O$_4$ (NC) were synthesized using the co-precipitation method. The samples were characterized by XRD, TXRF, TEM, and DRS, and their DC electrical conductivities were studied.

2. EXPERIMENTAL PROCEDURE

Distilled water (DW), cadmium nitrate terthylhydrate (Cd(NO$_3$)$_2$.4H$_2$O) (99%) (HIMEDIA), copper nitrate trihydrate (Cu(NO$_3$)$_2$.3H$_2$O) (98%) (HIMEDIA), cobalt nitrate hexahydrate (Co(NO$_3$)$_2$.6H$_2$O) (98%) (HIMEDIA), and Sodium hydroxide NaOH (98%) (HIMEDIA) were used in this research.

3. SYNTHESIS OF CdO-CuO-Co$_3$O$_4$ NANOCOMPOSITE

To synthesize CdO-CuO-Co$_3$O$_4$ (NC), a 0.03M precursor solution with a Cd:Cu:Co molar ratio of 1:1:1 was prepared by weighing 7.71g of Cd(NO$_3$)$_2$.4H$_2$O, 6.04 g of Cu(NO$_3$)$_2$.3H$_2$O, and 7.27g of Co(NO$_3$)$_2$.6H$_2$O and dissolving them all in 300 ml of distilled water under constant stirring for 10 min at ambient temperature. Then, a 0.1M NaOH solution was added dropwise to the mixed precursor solution to adjust its pH value to 7 while continuously stirring for 1 h. A precipitate was formed immediately. The precipitate was collected by filtration, washed several times with distilled water, and then dried at 100 °C for 1 h. Therefore, it was ground using a mortar and pestle to obtain a fine powder. Finally, the powder was annealed at 500 °C for 2 h to obtain NC. In a manner similar to that for the composites, individual pure oxides (CdO, CuO, and Co$_2$O$_3$) were separately prepared using the corresponding salt. Similarly, individual CdO, CuO, and Co$_2$O$_3$ (NPs) were produced using the co-precipitation technique, where 7.71g of Cd(NO$_3$)$_2$.4H$_2$O (or 6.04g of Cu(NO$_3$)$_2$.3H$_2$O or 7.27 g of Co(NO$_3$)$_2$.6H$_2$O) and 0.1 M NaOH were added to 100 ml of distilled water. Finally, brown of CdO (NPs) and black of CuO (NPs),Co$_2$O$_3$(NPs) and nanocomposite powders were formed as shown in Fig. 1.

4. CHARACTERIZATIONS

The structural properties of the prepared CdO, CuO, Co$_3$O$_4$ and CdO-CuO-Co$_3$O$_4$ (NC) were investigated using XRD technique (XD-2 X-ray diffractometer using CuK$_\alpha$ (\(\lambda = 0.154 \text{ nm}\)) at 36 kV and 20 mA, China). The concentrations of each element in the samples were measured using (TXRF) (xrf, S8 tiger, German) from the Yemeni Geological Survey and Minerals Resources Board. The nanoparticle size was determined using transmission electron microscopy TEM (JEM-2100, Japan) transmission electron microscope. The used particle size of The TEM was evaluated using the Image-J software. Using DR spectra over the wavelength range of 400–700 nm (Model: JASCO, V-750, Japan), the diffused reflectances of CdO, CuO, Co$_3$O$_4$ (NPs) and, CdO-CuO-Co$_3$O$_4$ (NC) were measured. The conductivities of the compounds were measured by a Keithley-6517B electrometer, (USA).

5. RESULTS AND DISCUSSION

5.1. STRUCTURAL ANALYSIS

The XRD patterns of the metal oxides CdO, CuO, Co$_3$O$_4$ (NPs), and CdO-CuO-Co$_3$O$_4$ (NC) are shown in Fig. 2. The XRD pattern of the NPs emphasized the presence of cubic CdO, Co$_3$O$_4$, and monoclinic CuO. The diffraction peaks matched well with the typical JCPDS Card No (01–1049) of CdO, (048-1548) of CuO, and (042-1467) of Co$_3$O$_4$. Diffraction peaks of CdO, CuO, and Co$_3$O$_4$
can be observed in the multi-metal oxide composite pattern, as shown in Fig. 2. Owing to the close diffraction angles, some of the diffraction peaks of the metal oxides in the XRD model of the composite were shifted. The peaks of CuO and Co$_3$O$_4$ in CdO-CuO-Co$_3$O$_4$ (NC) were higher intensity than those of CdO. Scherrer's equation, as expressed in Eq. (1) [27], was used to calculate the average crystallite size (D, nm) of CdO, CuO, Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC).

$$D = \frac{0.9 \lambda}{\beta \cos \theta},$$  \hspace{1cm} (1)

where $\lambda$ is the wavelength of the X-ray used, $\beta$ is the full-width at half maximum intensity (FWHM) (in radians), and $\theta$ is the diffraction angle.

Table 1 shows that the calculated value of D for CdO was greater than that for CuO and Co$_3$O$_4$. The crystallite sizes (D) of CdO, CuO, and Co$_3$O$_4$ in the nanocomposite decreased when compared to their size as nanoparticles, which indicates a decrease in the crystal growth of the nanocomposite. The micro-strain ($\epsilon$) and dislocation density ($\delta$) in the crystals were calculated using the relationships (2,3) [28]. The average crystallite size, dislocation density, and micro-strain for CdO, CuO, Co$_3$O$_4$ (NPs), and CdO-CuO-Co$_3$O$_4$ (NC) are listed in Table 1.

$$\epsilon = \frac{\beta}{4 \tan \theta},$$  \hspace{1cm} (2)

$$\delta = \frac{1}{D^2}.$$  \hspace{1cm} (3)

It is obvious that combining CdO, CuO, and Co$_3$O$_4$ (NPs) increases the dislocation density and decreases the grain size of the (NC). This result agrees with Munawar et al [29]. The decrease in the crystalline sizes is often associated with a higher density of defects and dislocations within the crystal lattice. These defects contribute to the microstrain by disrupting the regular atomic arrangement.

### Table 1. The values of D and $\epsilon$ of CdO, CuO, and Co$_3$O$_4$ (NPs) as well as CdO-CuO-Co$_3$O$_4$ (NC) determined using XRD analysis.

<table>
<thead>
<tr>
<th>Samples</th>
<th>D (nm)</th>
<th>$\epsilon \times 10^{-3}$</th>
<th>$\delta (nm^{-2}) \times 10^{-3}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Single metal oxides</td>
<td>CdO</td>
<td>37.73</td>
<td>1.7</td>
</tr>
<tr>
<td>CdO-CuO-CO$_3$O$_4$</td>
<td>CdO</td>
<td>32.26</td>
<td>3.8</td>
</tr>
<tr>
<td>Mixed metal oxides</td>
<td>CuO</td>
<td>24.9</td>
<td>4.9</td>
</tr>
<tr>
<td></td>
<td>Co$_3$O$_4$</td>
<td>16.1</td>
<td>13.1</td>
</tr>
</tbody>
</table>

### 5.2. Elemental Analysis

The results of the elemental chemical analysis of the prepared samples carried out using TXRF are listed in Table 2. CdO, CuO, and Co$_3$O$_4$ (NPs) constitute the majority of nanocomposite materials. Some impurities, including P, S, Ca, Fe, and Si, were present in trace amounts. This result is consistent with that of Jianfeng et al [30]. These results confirmed the purity of the prepared samples.

### Table 2. TXRF analysis of CdO-CuO-Co$_3$O$_4$ (NC).

<table>
<thead>
<tr>
<th>Compound</th>
<th>Wt %</th>
<th>Elemental</th>
<th>Wt %</th>
</tr>
</thead>
<tbody>
<tr>
<td>CuO</td>
<td>42.29%</td>
<td>Cu</td>
<td>39.14%</td>
</tr>
<tr>
<td>Co$_3$O$_4$</td>
<td>39.88%</td>
<td>Co</td>
<td>31.09%</td>
</tr>
<tr>
<td>CdO</td>
<td>17.38%</td>
<td>Cd</td>
<td>11.13%</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>O</td>
<td>18.19%</td>
</tr>
</tbody>
</table>
5.3. TEM ANALYSIS

The size and morphology of the synthesized nanoparticles and nanocomposites were determined using TEM, and the Image-J program was used to determine the particle sizes. TEM images of CdO, CuO, Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC) are shown in Fig. 3(a). Spherical particles with an average size of 60.8 nm, 70.7 nm and 33.4 nm were observed for CdO, CuO and Co$_3$O$_4$ (NPs) respectively. For the composite, the particles were agglomerated, and a mixture of particles, most of which were spherical and nanorod-shaped, could be detected. The average particle size of the composite was found to be 11.4 nm. The particle size of CdO-CuO-Co$_3$O$_4$ (NC) decreased compared to that of (NPs), which is in good agreement with previous studies [31]. The TEM results are consistent with the XRD results, which showed a reduction in the crystallite size of (NC) compared to that (NPs). Histogram graphs were shown in Fig. 3 (b).

5.4. OPTICAL STUDIES

5.4.1. Optical Band gap energy

The optical characteristics of CdO, CuO, Co$_3$O$_4$ (NPs, and CdO-CuO-Co$_3$O$_4$ (NC) materials were evaluated using diffuse reflectance spectroscopy. The reflectance spectra of the samples in the wavelength range of 400-700 nm are shown in Fig. 4 as a function of wavelength. The reflectance spectrum gradually decreased with increasing wavelength and then stabilized at a nearly constant value, except for CdO, where the reflection was at a constant low value and then increased with increasing wavelength. The absorbance was calculated by converting the measured reflectance using the Kubelka-Munk Eq. (4) [32].

$$F(R) = \frac{(1-R)^2}{2R},$$  \hspace{1cm} (4)

where R is the diffuse reflectance (%), and F (R) is the Kubelka-Munk function corresponding to the absorbance.

The following calculations were performed using the modified K-M equation to determine the material’s band gap energy ($E_g$) and the type of optical transition between the valence band (VB) and conduction band (CB):

$$F(R)h\nu = A(E - E_g)^n,$$  \hspace{1cm} (5)

where the constant $A$ depend on the transition possibility and measures the disorder of the material and band tailing, ($E=\hbar \nu$) is the photon energy, and the exponent factor $n$ is related to the nature of the optical transition and is equal to 1/2 for allowed direct optical transitions [32]. The band-gap values were determined by extrapolating the linear region of the plot to $E=0$. Tauc plots of ($F(R)h\nu)^2$ vs E. The optical band gaps ($E_g$) of CdO, CuO, Co$_3$O$_4$ (NPs), and CdO-CuO-Co$_3$O$_4$ (NC) are shown in Fig. 5 and Table 3.
Table 3. Optical energy band gaps ($E_g$) for CdO, CuO, Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC)

<table>
<thead>
<tr>
<th>Sample</th>
<th>$E_g$ (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CdO</td>
<td>2</td>
</tr>
<tr>
<td>CuO</td>
<td>1.5</td>
</tr>
<tr>
<td>Co$_3$O$_4$</td>
<td>1.16 &amp; 1.4</td>
</tr>
<tr>
<td>CdO-CuO-Co$_3$O$_4$</td>
<td>1.24</td>
</tr>
</tbody>
</table>

Figure 5. The plot of $(F(R) h\nu)^2$ vs $E$(ev) for direct band gap due to O$_2$ $\rightarrow$ CO$_2$, and O$_2$ $\rightarrow$ CO$_2^+$ charge transfer transition respectively [25]. The optical band gap of CdO-CuO-Co$_3$O$_4$ (NC) is lower than that of (NPs). This result was supported by the electrical resistivity measurements discussed below. The band-gap value of NC (1.24 eV) falls within the range of a narrow band-gap semiconductor, which is consistent with the results of previous studies [18, 33–35]. Materials with such band gaps have potential applications in photovoltaics, photocatalysis, and sensors.

5.4.2. Extinction coefficient and refractive index

The extinction coefficient ($k$) Eq. (6), also known as the absorption index, measures the quantity of light lost in a test material per unit distance due to absorption and scattering. It is possible to calculate $k$ using the optical absorption coefficient ($\alpha$) and event photon wavelength ($\lambda$) [29].

$$k = \frac{\alpha \lambda}{4\pi}.$$  

Eq. (7) can be used to determine the refractive index ($n$) of a crystalline solid from its reflectance ($R$) [36].

$$R = \frac{(n-1)^2 + k^2}{(n+1)^2 + k^2}.$$  

Where, $k$: is the extinction coefficient. Because of the small size of $k$, Eq. (8) can be changed to [36]:

$$n = \frac{1 + \sqrt{R}}{1 - \sqrt{R}}.$$  

According to Fig. 6(a) and 6(b), respectively, the $n$ and $k$ as functions of the photon energy supply, an analysis of the local field, and the ion's electronic polarizability. Based on the relation between ($n$) and the photon energy ($E$) as shown in Fig. 6(b), there are two types of dispersion: normal dispersion, which presents a direct proportional relation located in the energy range below 1.4 eV. The second type of dispersion is the anomalous dispersion for the reverse relation located above 1.4 eV. For all samples except CdO, the normal dispersion in the energy range is less than 1.2 eV and the anomalous dispersion is above 1.2 eV. The values of $k$ are very small compared with $n$. The extinction coefficient ($k$) and refractive index ($n$) off the nanocomposite decreased as the photon energy ($E$) increased.

Figure 6. (a): Absorption index ($k$) of the CdO-CuO-Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC) as a function of the photon energy. (b): Refractive index ($n$) of the CdO-CuO-Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC) as a function of the photon energy.
5.4.3. Optical conductivity

The optical conductivity $\sigma_{opt}$ is expressed as the optical response of the material to the spreading of charge carriers owing to the excitation caused by the event photon energy. The following equation states that the optical conductivity directly relies on the refractive index and absorption coefficient of the materials [37, 38].

$$\sigma_{opt} = \frac{n\alpha c}{4\pi}$$  \hspace{1cm} (9)

where $c$ is the speed of light in a vacuum. Figure 7 illustrates how the optical conductivity varies with the incident photon energy for CdO, CuO, CdO$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC). Figure 7 shows the optical conductivity increases at high photon energies. Owing to the excellent absorbent properties of the nanocomposite in this area, carriers were excited from the valence band to the conduction band, which resulted in higher value of $\sigma_{opt}$. It is obvious that the optical conductivity of CdO is between $0.21 \times 10^5$ and $1.78 \times 10^8$ (S$^{-1}$) and that the range of photon energies is (1–2.4 $\text{eV}$). The values of optical conductivity of CuO are between $0.42 \times 10^5$ and $1.74 \times 10^8$ (S$^{-1}$) and the range of photon energies (1–1.64 $\text{eV}$); the values of optical conductivity of Co$_3$O$_4$ are between $1.2 \times 10^6$ and $2.06 \times 10^8$ (S$^{-1}$) and the range of photon energies (1.2–1.7 $\text{eV}$); whereas the values of optical conductivity of CdO-CuO-Co$_3$O$_4$ (NC) are between $1.65 \times 10^6$ and $1.93 \times 10^8$ (S$^{-1}$) and the range of photon energies (1.43–1.82 $\text{eV}$). The highest value of $\sigma_{opt}$ was observed in the visible regions of CdO, CuO, Co$_3$O$_4$ (NPs) and CdO- CuO -Co$_3$O$_4$ (NC).

Figure 7. Optical conductivity on the photon energy for CdO,CuO,Co$_3$O$_4$ (NPs) and CdO-CuO-Co$_3$O$_4$ (NC)

5.5. Electrical studies

The DC electrical resistivity of the samples were studied as a function of temperature. The following equation was used to calculate the DC electrical resistivity ($\rho$) [39, 40].

$$\rho = \frac{V}{IL},$$  \hspace{1cm} (10)

where $I$ is the measured current, $V$ is the applied voltage, $L$ is the pellet thickness, and $A$ is the pellet cross-sectional area. The DC electrical resistivity decreased with the temperature as shown in Fig. 8. This figure shows how the electrical resistivity of the prepared sample changes with temperature. It was observed that the electrical resistivity decreased as the temperature increased, indicating the semiconducting behavior of the sample. It is clear that the mixed (NC) has lower resistivity (higher conductivity) than the single (NPs). This result is in accordance with the results of optical properties, where the lowest band gap energy was for NC; hence, the optical energy gap (Eg) decreases and the electrical conductivity increases. The result is in agreement with Munawar et al [29]. The temperature dependence of the DC resistivity $\rho_{DC}$ can be expressed by Arrhenius law [41]:

$$\rho_{DC} = \rho_o \text{Exp} \left(\frac{-E}{k_B T}\right),$$  \hspace{1cm} (11)

where $\rho_o$ is a constant, $k_B$ is Boltzmann’s constant, $T$ is the temperature in Kelvin, and $E$ is the activation energy.

The activation energies of CdO,CuO,CdO$_3$O$_4$ and CdO-CuO-Co$_3$O$_4$ (NC) were computed from $\ln \rho$ and $1/T$, as shown in Fig. 9, and the obtained values are given in Table 4, which is consistent with previous study results [42–44]. The previous results clearly show that the...
Table 4. Values of the activation energies of a CdO, CuO, Co$_2$O$_4$ (NPs) and CdO-CuO-Co$_2$O$_4$ (NC)

<table>
<thead>
<tr>
<th>Samples</th>
<th>$E$ (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CdO</td>
<td>0.183</td>
</tr>
<tr>
<td>CuO</td>
<td>0.211</td>
</tr>
<tr>
<td>Co$_2$O$_4$</td>
<td>0.357</td>
</tr>
<tr>
<td>CdO-CuO-Co$_2$O$_4$</td>
<td>0.151</td>
</tr>
</tbody>
</table>

activation energy decreased with the mixture.

Figure 9. variation of lnP with $\frac{1}{T}$ ($k^{-1}$) for the CdO,CuO,Co$_2$O$_4$ (NPs) and CdO-CuO-Co$_2$O$_4$ (NC) at different temperature of annealing

6. CONCLUSION

CdO, CuO, Co$_2$O$_4$ (NPs) and CdO-CuO-Co$_2$O$_4$ (NC) were effectively prepared using the co-precipitation method. Cubic structured CdO, Co$_2$O$_4$, and monoclinic structured CuO peaks were found in the XRD pattern of the composite. The highest peaks in the XRD patterns were observed for CuO, whereas the lowest peaks were for CdO. The TEM image shows that the particle size of the nanocomposites was 11.4 nm. The XRD and TXRF results confirmed the purity of the samples. The optical bandgap of the (NC) is 1.24 eV. The DC resistivity measurements showed typical semiconducting behavior for (NPs) and (NC) samples, where the electrical resistivity decreased as the temperature increased.

REFERENCES

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